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THIRD SERIES, VOLUME 56, NUMBER 19 ***CONTENTS*** **15 NOVEMBER 1997-I**

BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Low-energy restoration of Fermi-liquid behavior for two-channel Kondo scattering 12 033
Shashi K. Upadhyay, Richard N. Louie, and R. A. Buhrman
Transmission and reflection from a disordered lasing medium 12 038
Sandeep K. Joshi and A. M. Jayannavar
Significance of the highest occupied Kohn-Sham eigenvalue 12 042
Leonard Kleinman
Effects of doping and magnetic field on the half-metallic electronic structures of $La_{1-x}Ba_xMnO_3$ 12 046
S. J. Youn and B. I. Min
Unconventional spectral changes across the metal-insulator transition in $CeTiO_{3+\delta}$ 12 050
O. Akaki, A. Chainani, T. Yokoya, H. Fujisawa, T. Takahashi, and M. Onoda
Resonant photoemission study of the $4f$ spectral function of cerium in Ce/Fe(100) interfaces 12 054
N. Witkowski, F. Bertran, T. Gourieux, B. Kierren, D. Malterre, and G. Panaccione
Exchange-correlation functional based on the density matrix 12 058
A. E. Carlsson
Irreversible electrical resistivity and unstable bonding nature in the fast-Li-ion conductor β-LiGa 12 062
K. Kuriyama, H. Hamanaka, R. Taguchi, and M. Yahagi

Semiconductors I: bulk

Grain-boundary defects in laser-crystallized polycrystalline silicon 12 065
N. H. Nickel, G. B. Anderson, and R. I. Johnson
Stimulated far-infrared emission from combined cyclotron resonances in germanium 12 069
L. A. Reichertz, O. D. Dubon, G. Sirmain, E. Bründermann, W. L. Hansen, D. R. Chamberlin, A. M. Linhart, H. P. Röser, and E. E. Haller
Zeeman spectroscopy of shallow donors in GaN 12 073
W. J. Moore, J. A. Freitas, Jr., and R. J. Molnar
Magnetization of bound magnetic polarons in Ga-doped $Cd_{1-x}Mn_xTe$ 12 077
Jolanta Stankiewicz and Fernando Palacio

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Extremely long surface diffusion of Ga and critical nucleation on As-rich GaAs(001) surfaces caused by phase transitions 12 080
Kiyoshi Kanisawa and Hiroshi Yamaguchi
Ab initio calculation of the structure of the random alloys Sn_xGe_{1-x} 12 084
Jianhua Shen, Jian Zi, Xide Xie, and Ping Jiang
Energy spectrum for two-dimensional potentials in very high magnetic fields 12 088
Z. Gedik and M. Bayindir
Ultrafast electron transport in layered semiconductors studied with femtosecond-laser photoemission 12 092
Armin Rettenberger, Paul Leiderer, Matthias Probst, and Richard Haight
Enhanced exciton-phonon scattering in $In_xGa_{1-x}As/GaAs$ quantum wires 12 096
W. Braun, M. Bayer, A. Forchel, H. Zull, J. P. Reithmaier, A. I. Filin, and T. L. Reinecke

(Continued)

0163-1829(19971115)56:19;1-T

PHYSICAL REVIEW B THIRD SERIES, VOLUME 56, NUMBER 19 15 NOVEMBER 1997-I

Luminescence detection of nonequilibrium phonons in $CdTe/Cd_{0.6}Mn_{0.4}Te$ semimagnetic quantum wells 12 100
A. V. Akimov, A. V. Scherbakov, A. L. Zhmodikov, V. P. Kochereshko, D. R. Yakovlev, W. Ossau, G. Landwehr, T. Wojtowicz, G. Karczewski, and J. Kossut

Theory of conductance and noise additivity in parallel mesoscopic conductors 12 104
G. Iannaccone, M. Macucci, and B. Pellegrini

Density-functional theory of the phase diagram of maximum-density droplets in two-dimensional quantum dots in a magnetic field 12 108
M. Ferconi and G. Vignale

Coulomb-like mesoscopic fluctuations in a two-dimensional electron gas near filling factor $\nu=\frac{1}{2}$ 12 112
Z. D. Kvon, E. B. Olshanetsky, G. M. Gusev, J. C. Portal, and D. K. Maude

Unpolarized quasielectrons and the spin polarization at filling fractions between $\nu=1/3$ and $\nu=2/5$ 12 116
Jacek Dziarmaga and Meik Hellmund

Nonlinear transport in quasi-two-dimensional systems driven by intense terahertz fields 12 120
X. L. Lei, B. Dong, and Y. Q. Chen

Surface physics, low-dimensional systems, and related topics

Transition of an adsorption state of C_{60} on a Si(111)7×7 surface revealed by high-resolution electron-energy-loss spectroscopy 12 124
Yasunori Fujikawa, Koichiro Saiki, and Atsushi Koma

H- and Li-induced (2×2)-to-(2×1) phase transitions on diamond C(111) 12 127
M.-H. Tsai, J. C. Jiang, and S. H. Lin

Flatness and shape of (111) facets of equilibrated Pb crystals 12 131
S. Surnev, P. Coenen, B. Voigtländer, H. P. Bonzel, and P. Wynblatt

Step roughening effect on adatom diffusion 12 135
O. S. Trushin, K. Kokko, P. T. Salo, W. Hergert, and M. Kotrla

Surface-layered ordered alloy (Pt/Pt_3Mn) on Pt(111) 12 139
S. Gallego, C. Ocal, M. C. Muñoz, and F. Soria

Electronic properties of fullerenes with nonpositive Gaussian curvature: Finite zeolites 12 143
J. L. Ricardo-Chávez, J. Dorantes-Dávila, M. Terrones, and H. Terrones

Magic triangular and tetrahedral clusters 12 147
S. M. Reimann, M. Koskinen, H. Häkkinen, P. E. Lindelof, and M. Manninen

ARTICLES

Electronic structure: wide-band, narrow-band, and strongly correlated systems

Shielding factors of ions in rock-salt crystals 12 151
Y. Michihiro and G. D. Mahan

Jahn-Teller distortion and magnetic structures in $LaMnO_3$ 12 154
H. Sawada, Y. Morikawa, K. Terakura, and N. Hamada

Charge redistribution at Pd surfaces: *Ab initio* grounds for tight-binding interatomic potentials 12 161
S. Sawaya, J. Goniakowski, C. Mottet, A. Saúl, and G. Tréglia

Theory for the electromigration wind force in dilute alloys 12 167
J. P. Dekker, A. Lodder, and J. van Ek

Determination of charge transfer in the Cu_xPd_{1-x} alloy system 12 178
R. J. Cole, N. J. Brooks, and P. Weightman

Gap-opening transition and fractal ground-state phase diagram in one-dimensional fermions with long-range interaction: Mott transition as a quantum phase transition of infinite order 12 183
Yasuhiro Hatsugai

(Continued)

PHYSICAL REVIEW B THIRD SERIES, VOLUME 56, NUMBER 19 15 NOVEMBER 1997-I

Enhanced electron-lattice coupling in $La_{1-x}Sr_xMnO_3$ near the metal-insulator phase boundary 12 190
Y. Moritomo, A. Asamitsu, and Y. Tokura
Characterization of the bipolar mobility in polar materials by interband photoexcitation 12 196
Pietro Bernasconi, Germano Montemezzani, Ivan Biaggio, and Peter Günter
Variational quantum Monte Carlo calculation of the cohesive properties of cubic boron nitride 12 201
A. Malatesta, S. Fahy, and G. B. Bachelet
Change of IR spectra of $Ba_{1-x}K_xBiO_3$ crystals at the low-temperature phase transition 12 211
M. E. Kozlov, Xiaoli Ji, H. Minami, and H. Uwe
Localization of two interacting particles in a one-dimensional random potential 12 217
P. H. Song and Doochul Kim
Localization in weakly coupled planes and weakly coupled wires 12 221
I. Zambetaki, Qiming Li, E. N. Economou, and C. M. Soukoulis
Unoccupied electron states of TiS_2 studied by means of polarized x-ray absorption 12 232
A. Šimůnek, O. Šipr, S. Bocharov, D. Heumann, and G. Dräger
Energy dependence of Cu $L_{2,3}$ satellites using synchrotron excited x-ray-emission spectroscopy 12 238
M. Magnuson, N. Wassdahl, and J. Nordgren

Semiconductors I: bulk

Molecular-dynamics study of surface segregation in liquid semiconductor alloys 12 243
Wenbin Yu and D. Stroud
Direct calculation of Slater-Koster parameters: Fourfold-coordinated silicon/boron phases 12 250
A. K. McMahan and J. E. Klepeis
Fixed-spin-induced ESR linewidth and polaron mobility in conducting polymers 12 263
E. Houzé, M. Nechtschein, and A. Pron
Off-diagonal interactions, bond density correlation, and their effects on the excitons in conjugated polymers 12 268
Hua Zhao, Rong-tong Fu, Xin Sun, and Zhi-lin Zhang
Resonant optical nonlinearity of conjugated polymers 12 277
Ming-Che Chang and Hsin-Fei Meng
Dynamical density response of II-VI semiconductors 12 285
A. Fleszar and W. Hanke
Structural and vibrational properties of Si clathrates in a generalized tight-binding molecular-dynamics scheme ... 12 290
Madhu Menon, Ernst Richter, and K. R. Subbaswamy

Semiconductors II: surfaces, interfaces, microstructures, and related topics

Growth of GaSe ultrathin films on Si(111) substrates analyzed by the x-ray standing-wave technique 12 296
A. Koëbel, Y. Zheng, J. F. Pétroff, J. C. Boulliard, B. Capelle, and M. Eddrief
Migration of subsurface self-interstitial atoms of the Ge(113) surface and the energy barrier 12 303
Zheng Gai, R. G. Zhao, and W. S. Yang
Atomic structure of high-index Ge surfaces consisting of periodic nanoscale facets 12 308
Zheng Gai, R. G. Zhao, Hang Ji, Xiaowei Li, and W. S. Yang
Initial stages of Au adsorption on the Si(111)-(7×7) surface studied by scanning tunneling microscopy 12 316
Ilya Chizhov, Geunseop Lee, and Roy F. Willis
Electronic structure of wurtzite II-VI compound semiconductor cleavage surfaces studied by scanning tunneling microscopy 12 321
B. Siemens, C. Domke, Ph. Ebert, and K. Urban
Angular-momentum photon-drag current in a mesoscopic metallic cylinder shell 12 327
Ole Keller and Gang Wang
ac response of a double quantum dot 12 339
Tzanko Ivanov

(Continued)

PHYSICAL REVIEW B THIRD SERIES, VOLUME 56, NUMBER 19 15 NOVEMBER 1997-I

Harmonic-solid theory of photoluminescence in the high-field two-dimensional Wigner crystal 12 344
S. Kodiyalam, H. A. Fertig, and S. Das Sarma
Magnetic-field-induced localization of carriers in $Al_{0.25}Ga_{0.75}As/AlAs$ multiple-quantum-well structures 12 364
J. Haetty, M. Salib, A. Petrou, T. Schmiedel, M. Dutta, J. Pamulapati, P. G. Newman, and K. K. Bajaj
Elastic and plastic strain relaxation in ultrathin CdS/ZnS quantum-well structures grown by molecular-beam epitaxy 12 369
M. Hetterich, M. Grün, W. Petri, C. Märkle, C. Klingshirn, A. Wurl, U. Fischer, A. Rosenauer, and D. Gerthsen
Far-infrared edge modes in quantum dots 12 375
E. Lipparini, N. Barberán, M. Barranco, M. Pi, and Ll. Serra
Theory of photoluminescence from an interacting two-dimensional electron gas in strong magnetic fields 12 386
Pawel Hawrylak and Marek Potemski
Magnitude and size scaling of intervalley coupling in semiconductor alloys and superlattices 12 395
Lin-Wang Wang and Alex Zunger
Charging ultrasmall tunnel junctions in an electromagnetic environment 12 404
X. H. Wang and K. A. Chao
Fermi-sea-like correlations in a partially filled Landau level 12 411
R. K. Kamilla, J. K. Jain, and S. M. Girvin
Composite fermion hierarchy: Condensed states of composite fermion excitations 12 417
P. Sitko, K.-S. Yi, and J. J. Quinn
Thermoelectric and hot-electron properties of a silicon inversion layer 12 422
R. Fletcher, V. M. Pudalov, Y. Feng, M. Tsaousidou, and P. N. Butcher
In- and out-going resonant Raman scattering from the cavity polaritons of semiconductor quantum microcavities 12 429
W. R. Tribe, D. Baxter, M. S. Skolnick, D. J. Mowbray, T. A. Fisher, and J. S. Roberts
Effects of microwave electric fields on the luminescence of *n*- and *p*-type GaAs 12 434
C. E. Inglefield, M. C. DeLong, P. C. Taylor , and W. A. Harrison
Isotope scattering of phonons in superlattices 12 440
Shin-ichiro Tamura
Optical anisotropy of excitons in strained GaN epilayers grown along the $\langle 10\bar{1}0 \rangle$ direction 12 446
Bernard Gil and Andenet Alemu
Excitonic trion X^- in semiconductor quantum wells 12 454
B. Stébé, G. Munschy, L. Stauffer, F. Dujardin, and J. Murat
Low-frequency quantum transport in a three-probe mesoscopic conductor 12 462
Qingrong Zheng, Jian Wang, and Hong Guo

Surface physics, low-dimensional systems, and related topics

Nonperturbative evaluation of STM tunneling probabilities from *ab initio* calculations 12 469
H. Ness and A. J. Fisher
Self-lubrication in scanning-force-microscope image formation on ionic surfaces 12 482
Alexander I. Livshits and Alexander L. Shluger
Scanning tunneling microscope investigation of carbon nanotubes produced by catalytic decomposition of acetylene 12 490
L. P. Biró, S. Lazarescu, Ph. Lambin, P. A. Thiry, A. Fonseca, J. B. Nagy, and A. A. Lucas
Relaxation of surface profiles by evaporation dynamics 12 499
Johannes Hager
In situ STM study of the electrodeposition and anodic dissolution of ultrathin epitaxial Ni films on Au(111) 12 506
F. A. Möller, J. Kintrup, A. Lachenwitzer, O. M. Magnussen, and R. J. Behm
Ordering of clusters during late-stage growth on surfaces 12 519
G. R. Carlow, R. J. Barel, and M. Zinke-Allmang

(Continued)

PHYSICAL REVIEW B THIRD SERIES, VOLUME 56, NUMBER 19 15 NOVEMBER 1997-I

Effects of surface impurities on surface diffusion of CO on Ni(110) 12 529
Xudong Xiao, Yuanlin Xie, Christian Jakobsen, and Y. R. Shen
Transition from one- to two-dimensional island growth on metal (110) surfaces induced by anisotropic corner rounding 12 539
Yinggang Li, M. C. Bartelt, J. W. Evans, N. Waelchli, E. Kampshoff, and K. Kern
Surface energetics from the transition from step-flow growth to two-dimensional nucleation in metal homoepitaxy 12 544
Ivan Markov
XANES of high-pressure Kr clusters in Be and Si 12 553
Giuseppe Faraci, Agata R. Pennisi, and Jean-Louis Hazemann
Unified behavior of alkali core-level binding-energy shifts induced by *sp* metals 12 560
E. Lundgren, R. Nyholm, M. Qvarford, J. N. Andersen, D. Heskett, and S. V. Christensen
Conductance quantization in metals: The influence of subband formation on the relative stability of specific contact diameters 12 566
J. M. van Ruitenbeek, M. H. Devoret, D. Esteve, and C. Urbina
Islanding and strain-induced shifts in the infrared absorption peaks of cubic boron nitride thin films 12 573
S. Fahy, C. A. Taylor II, and R. Clarke
Coherent optical nonlinearities and phase relaxation of quasi-three-dimensional and quasi-two-dimensional excitons in ZnS_xSe_{1-x}/ZnSe structures 12 581
H. P. Wagner, A. Schätz, R. Maier, W. Langbein, and J. M. Hvam
Structural and electronic properties of Ce overlayers and low-dimensional Pt-Ce alloys on Pt{111} 12 589
Christopher J. Baddeley, Andrew W. Stephenson, Christopher Hardacre, Mintcho Tikhov, and Richard M. Lambert
Real-space formulation of the quantum-mechanical elastic diffusion under *n*-fold axially symmetric forces 12 599
A. Mayer and J.-P. Vigneron
Pattern formation during electropolishing 12 608
Vadim V. Yuzhakov, Hsueh-Chia Chang, and Albert E. Miller
Molecular fluorescence at a rough surface: The orientation effects 12 625
W. L. Blacke and P. T. Leung
Yielding and fracture mechanisms of nanowires 12 632
H. Mehrez and S. Ciraci

COMMENTS

Comment on ''Temperature dependence of electronic states in $(TaSe_4)_2I$'' 12 643
R. Claessen, C. Wilde, F. Reinert, S. Hüfner, G.-H. Gweon, J. W. Allen, D. M. Poirier, and C. G. Olson
Reply to ''Comment on 'Temperature dependence of electronic states in $(TaSe_4)_2I$' '' 12 647
A. Terrasi, M. Marsi, H. Berger, G. Margaritondo, R. J. Kelley, and M. Onellion
Comment on ''Thermopower and conductivity activation energies in hydrogenated amorphous silicon'' 12 649
H. Overhof, W. Beyer, and P. Thomas

Errata

Erratum: Effect of zero-point corrections and *k*-point sampling on the structural stability determinations of alkali metals [Phys. Rev. B **54**, 10 253 (1996)] 12 651
N. Tugluoglu and R. H. Mutlu
Erratum: Optical properties of graphite from first-principles calculations [Phys. Rev. B **55**, 4999 (1997)] 12 652
R. Ahuja, S. Auluck, J. M. Wills, M. Alouani, B. Johansson, and O. Eriksson
Erratum: Theory of exciton pair states and their nonlinear optical properties in semiconductor quantum dots [Phys. Rev. B **55**, 5153 (1997)] 12 652
Selvakumar V. Nair and Toshihide Takagahara

(Continued)

PHYSICAL REVIEW B **THIRD SERIES, VOLUME 56, NUMBER 19** **15 NOVEMBER 1997-I**

Erratum: Theoretical study of the high-pressure phase stability of GaP, InP, and InAs [Phys. Rev. B **55**, 9659 (1997)] 12 653
A. Mujica and R. J. Needs

Cumulative Author Index 12 655